

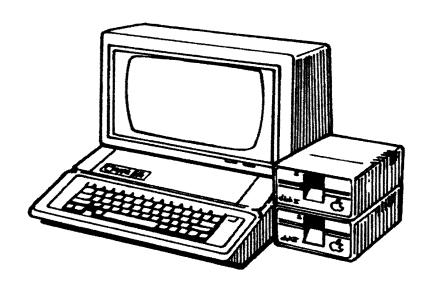
Apple][Computer Information

IWM Floppy Disk I/O Controller Info

Engineering Drawing # 343-0041-A IC -- Integrated Woz Machine (IWM)

Bob Bailey -- Apple Computer, Inc. -- February 28, 1984

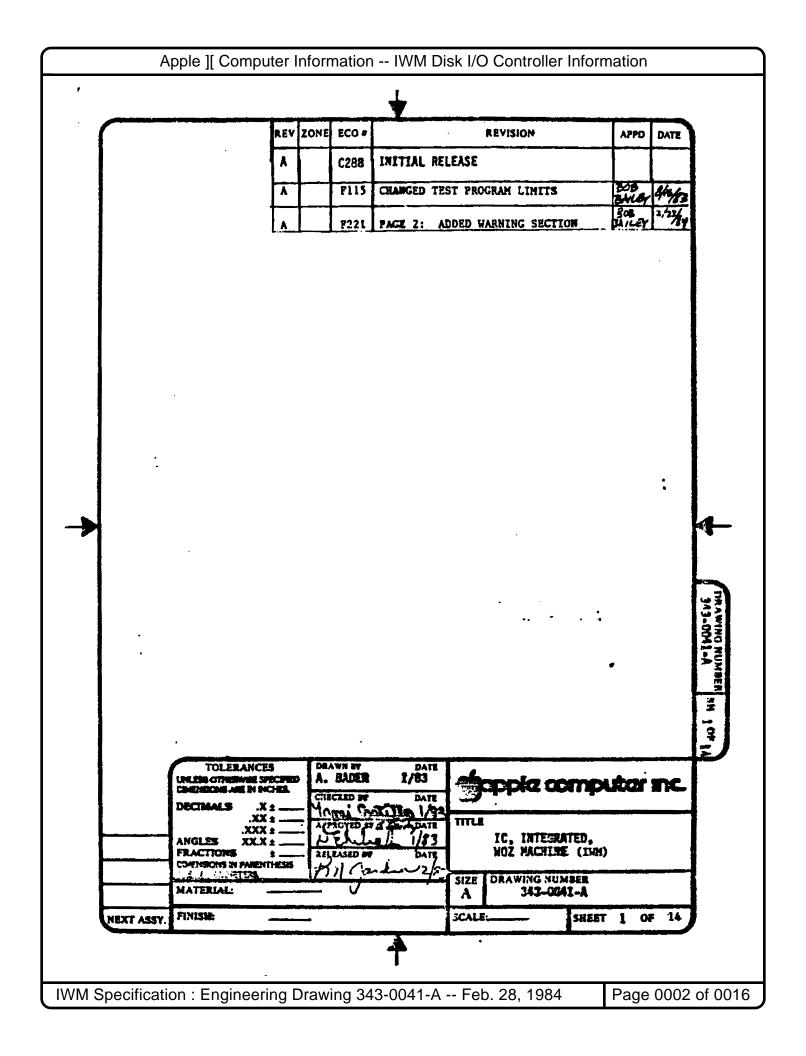
INCLUDES DISK II ANALOG BOARD SCHEMATIC



SOURCE
Brutal Deluxe Software web site -- www.brutal-deluxe.fr
31 December 2008

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Integrated WOZ Machine (IWM)

Device Specification

Features

- * Backwards-compatible with 16 sector Disk 1[controller
- * Use of 7M (or 8 mHz) to minimize sampling error rate
- * Fast mode using 2 uS bit cells
- * Asynchronous mode with pollable handshake registers

WARNING

The IWM will not work reliably in synchronous mode with the 6502 using Apple II disk software. It will work with the CHOS version done by Western Design Center (MCR supplies this part as MCR65C02).

During the load accumulator instruction, if the B7 entput of the IVM changes to 1 just before the end of the microprocessor read window, the MEGATIVE flag may be set but A[7] remain 0. This results in recognition of a "valid" byte. The accumulator will contain the byte except A[7] will be incorrect. The difference between the \$502 and the \$5002 is that the latter uses regenerative feedback to force the latched input data to valid logic levels after the read window ends. This guarantees the MEGATIVE flag and A[7] will be equal after the load accumulator instruction.

The 6502 may be used if A[7] is not used in the de-nibblising process. A simple fix to the current routines is to force A[7] to a 1 by ORA #580 after reading the nibble.

General Description

The IWH is an integration of the Disk II floppy disc interface. When the IWH is reset, it becomes a controller compatible with the current Disk II interface in its operation with currently supported Apple II and /// software. In addition, the IWH has extensions including a status register, node register, and sultiple nodes of operation. The IWH provides an asynchronous mode, a fast mode with a data rate twice that of Disk II, and an optional 1 second one-shot timer to hold the enable outputs low.

The IVM is a peripheral device that connects to a host data bus. The device generates and receives serial GCR encoded data. A programmable digital one shot is used for serial data recovery. The IVM generates buffered drive enables and phase line control outputs.

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Packaging and Pin Assignment

The IWM is packaged in a standard 28 pin, 600 mil plastic DIP.

			
PHASE O	1 1	28[PHASE E
PHASE 2	Z	27	PHASE 3
AO	1 3	26	Vec
A1	4	25	Q3
A2	5	24	FCLK
A3	6	23	/reset
/DEA	17	22	RDDATA
WRDATA	1 8	21]	sense.
/WRREQ	9	20	/ENBLE
D0	110	19	/ENBL2
Dl	111	18	07
D2	112	17	D6
D3	113	161	D5
GND	14	15	D4
	+		

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Technical Description

The primary purpose of the IWM is to allow a microprocessor to read and write serial GCR (group code) encoded data. The IWM may be controlled by setting state bits and reading or writing registers. Setting a state bit and accessing a register is done simultaneously. The registers are the mode register, the status register, the write-handshake register, the read data register, and the write data register. The modes selected by the mode register include synchronous or asynchronous mode and slow or fast mode.

The data format is an 8 bit nibble with the MSB set. The MSB of the 8 bit data nibble is shifted in or written out first. A bit is transferred every bit cell time. The bit cell time defaults to 4 uS (set to 2 uS in fast mode). Therefore the data rate is one nibble every 32 uS (16 uS in fast mode). When writing data out, a one is written as a transition on the WRDATA output at a bit cell boundary time and a zero is written as no transition.

The IWM is put into the write state by a transition from the write protect sense state to the write load state. In the synchronous mode, the time of that transition and every 8 Q3 periods (4 u5) thereafter, until L7 is cleared, marks the beginning of a write window. The duration of the write window is 4 periods of the Q3 input signal (2 u5). The data written at the last write access occurring within this write window will load the shift register with the data to be shifted out. If the next write access has not occured 32 u5 (64 Q3 periods) after a load, the write will be extended in multiples of 4 uS (8 Q3 periods) until another write access, and zeros will be shifted out.

In synchronous mode, Q3 clock input is used internally to generate the 32 and 40 uS timings, which would then be 64 and 30 of the Q3 clock input periods in duration, respectively, and the bit cell timings, 8 Q3 periods per bit cell time in slow mode.

In asynchronous mode the write shift register is buffered and, when the buffer is empty, the IMM sets the MSB of the write-handshake register to a one-to indicate that the next data nibble can be written to the buffer. The buffer register may be written at any time during the write state. Only the data last written into the buffer register, before the contents of the buffer register is transferred to the write shift register, is used.

In asynchronous mode CLK is used to generate the bit cell timings. In fast mode the CLK clock is equivalent to the clock input on FCLK. In slow mode CLK is equivalent to the clock input on FCLK divided by two. Therefore, in 7M and slow mode the bit cell time will be 28 FCLK clock input periods in duration, in 8M and slow mode the cell time will be 32 periods, and in 8M and shift register is loaded every 8 bit cell times starting seven CLK periods after the write state begins.

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343-0041-A Sheet 4 of 14 An underrun occurs when data has not been written to the buffer register between the time the write-handshake bit indicates an empty buffer and the time the buffer is transferred to the write shift-register. If an underrun occurs in asynchronous mode /WRKEQ will be disabled (set to a TTL high state) and the /underrun flag will be set to zero. This occurrance can be detected by reading the write-handshake register before clearing state bit L7. Clearing state bit L7 will reset the /underrun flag.

When L6 and L7 are both zero the IWM is in the read state. When reading serial data, a falling transition within a bit cell window is considered to be a zero. The receive data input on RDDATA is synchronized internally with the CLK clock. The synchronized falling transition is then discriminated to the nearest bit cell window using the 7/8 mHz FCLK clock signal in fast mode and the FCLK signal divided by two in slow mode. A digital one-shot data recovery scheme is used. Every falling transition establishes the bit cell windows, used by the data seperator in the IWH to recover the following bits, until another falling transition is received.

In the read state the data is shifted into the LSB of the shift register, and the shift register shifts data from LSB to MSB. A full data nibble is considered to be shifted in when a one is shifted into the MSB. When a full data nibble is shifted into the internal shift register, the data will be latched by the read data register and the shift register will be cleared to all zeros so that it will then be ready to shift in the next data word.

In the synchronous mode the shift register is readable in any intermediate state with this exeception: when a one is shifted into the MSB, the shift register will appear, to the data bus, to be stalled for a period of two bit times plus four CLK periods. This is to allow the host processor time to poll the MSB to determine when data is valid. In asynchronous mode the data register will latch the shift register when a one is shifted into the MSB and will be cleared 14 FCLK periods (about 2 uS) after a valid data read takes place (a valid data read being defined as both /DEV being low and D7 (the msb) outputting a one from the data register for at least one FCLK period).

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Read data bit cell windows

mode		Nelks	period	data	notes
slow	7H	7-2# 21-34 35-48	FCLK/2	1 Ø1 Ø61	2.0-5.71+ us 6.0-9.71+ us 10.0-13.71+ us
slow	8H	8-23 24-39 46-55	FCLK/2	1 61 66;	window is 28 clks
fact	7:€	7-25 21-34 35-48	FCLK	1 61 661	window is 14 clks
fast	K8	8-23 24-39 4 <i>8</i> -55	FCLR	1 91 991	1.0-2.875+ uS 3.0-4.75+ uS 5.0-6.875+ uS vindow is 16 clks

The table above shows how the data separator in the IWM discriminates between ones and zeros when reading. Nolks is the number of clock periods between falling transitions of the internally synchronous version of RDDATA. The clock period is either that of the FCLK input or that of the FCLK input divided by two in slow mode. Each falling transition resets the read data windows for subsequent data to be relative to that transition. The data patterns noted above are the bit patterns that are shifted in as a result of the transitions and the absence of transitions in their respective windows.

In port operation, which is seynchronous mode true and latch mode false with /DEY held low indefinitely, read data will appear and change as if the IWM were being continually read. In port operation the MSB can be used to continually clock data into external registers. The MSB will be cleared at least six FCLK periods before being set. Except in port operation, in asynchronous mode the latch mode bit should be set (for reliability in clearing the data register after a read).

Data written to the IWM is sampled by the zaro to one transition of the logical OR of Q3 and /DEV . In asynchronous mode the Q3 input may be tied low.

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1.

Signal and Bus operation Description

1. Vcc +5 volt supply
Ground reference and negative supply

2. Device Control Signals

Al-A3

These three inputs select one of the 8 bits in the state register to be updated.

AB

The data input to the state bit selected by Al-A3. The state to which the addressed state bit is set by an operation will select the register to be accessed by that operation.

Also the /READ input. A low on this input enables the IWM to send the register selected by se state onto the data bus.

DØ-D7

The bidirectional data bus .

/DEV

Active low device enable. The falling edge of /DEV latches information on AD-A3. The rising edge of the logical function (Q3 OR /DEV) qualifies write register data.

FCLK

Clock input for the serial data logic; either 7 or 8 MHz.

Q3

2.5 Mhz clock input used to qualify the timing of the serial data being written out in the synchronous mode.

/RESET

Active low system reset input.
When asserted, this signal places all IWM outputs in their inactive state, and sets the state and the modes to their defaults.

3. Inputs (2)

RDDATA

The serial data input. The falling transition of each pulse is synchronized by the IWM.

SENSE

An input to the IWM that can be polled via the status register.

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4. Outputs (8)

WRDATA

The serial data output. A transition occurs on this output for each one bit.

/ENBL1 . /ENBL2

Programmable buffered output lines. No more than one enable may be low at any time. If an enable is low than Motor-On is true.

If the 1-second on board timer is enabled then the selected one will stay low for about 1 second after it is programmed high.

/WRREQ

This signal is a programmable buffered output line.

PHASES-3

These are programmable output lines. A true TTL logic "1" (2.4 volts) can be-maintained even while driving two darlington inputs in parallel.

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Register Description

State Register

This is an 8-bit write-only pseudo-register. The bits in this register are individually addressed by A3,A2,A1. The data on AB is latched into the addressed state bit by /DEV low. All eight state bits are reset to 9 by /RESET low.

Not only do the state bits control certain chip functions and outputs, the setting of two of the state bits L6 and L7, and Motor-On, internally select which register is to be selected and whether the operation is to be a read or a write. If an operation occurs that changes the state of one of these bits to a new state, that new state will select the register to be accessed during that operation and whether that operation is to be a read or a write.

Address	Name	Function
1 2		A l in this bit will drive PHASES to a high state. PHASE1 PHASE2
3 4 5 6 7	LMotor-On Drive-Sel L6 L7	PHASE3 A I on LHotor-On sets the enable selected below low A I on this bit selects /ENBL2; a ß selects /ENBL1 (see description below) (see description below)

The state bits L7 and L6, and Motor-On, select which register is available to be read or written. Other registers are read during any operation in which set to 1 and A5 is a one.

The combination of L7 and Motor-On and Junderrun enables /WRREQ low.

L7	16	Hotor-On	register operation selected	State Name
9 9 1 1 1	5 1 5 1	# 1 * * # 1	read all ones read data register read status register read write-handshake register write mode register write data register	Read Write-Protect Sense Write Mode Set Write Load

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Hode register (a write only register)

All eight mode bits are reset to \$ by /RESET low.

In latch mode the mab of the read data is latched internally during /DEV low (this internally latched mab is then used for the determination of a valid data read).

If the I-second timer bit is a zero then the enable (/ENBL1 or /ENBL2) selected by Drive-Sel will be held low for 2°23 +-166 FCLK periods (about 1 second) after the LMotor-On state bit is reset to zero. If the latch mode bit is set the timer is not guaranteed to count up to 2°23. Motor-On is synonomous with either /ENBL1 or /ENBL2 being low.

Fast mode selects a bit cell time of 2 uS instead of 4 uS. The 7/8 mHz descriptor indicates whether the input clock (FCLK) is to be divided by 7 or 8 to provide 1 uS internal timings.

When the test mode bit is a 1, device operation is unspecified, except that status register bit 5 can always be read and that the mode register can always be set.

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```
( a read-only register )
1
mode register
wer /ENBL1 or /ENBL2 is currently active (low)
    ( reset to 9 by /RESET and MZ-reset )
E input high; $ = SENSE input low
ed for compatibility with future products and should
( a read only register )
for future use (currently read as ones)
a state ( cleared to Ø if a write underrun occurs )
e data buffer register ready for data
data register depends on the setting of state bits L6
mous mode bit. With L6 and L7 clear, the data
ead data register. With L7 set the data register
ite as a write data buffer.
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Maximum Ratings

supply voltage
finput voltage
finput voltage
storage temperature
operating temperature
-35 to +7.0 v
-35 to +125 degrees C
operating temperature
f to +70 degrees C (ambient)

DC characteristics

\$ym	parameter	nin	MAX	units	notes
Vcc Icc Vil Vih Il Vol Voh Ioh	supply voltage supply current Input low Input high input leakage TTL output low TTL output high source current at Voh sink current at Vol	4.75 2.\$ 2.4 .32 3.2	5.25 60 9.8 — 100 .4 —	Volts MA V V UA V MA MA	5 3 4 1

Notes

1. Inputs.

The inputs have static protection. All IWM inputs and bidirectional lines in the input mode are high impedance except as noted below:

WPROT and /RDDATA: pullup to VCC of 10K ohus nominal (source current of 80 to 600 uA at 0 Volts with VCC = 5.25V

 Outputs Ioh and Iol apply to DØ thru D7 and WRDATA. The following output lines have special drive capabilities, noted below.

/ENBL1, /ENBL2: Sink current of at least 5.8 mA at Vol Source current of at least 40 uA at Voh Sink current of at least 10.8 mA at Vol Source current of at least 40 uA at Voh

PHASE 0, PHASE 2 Source current of at least 1.8 mA at Voh
Source current of 8.5 mA when pulled down to 3.8 V.
Sink current of at least 2.4 mA at Vol

PHASE 1: Source current of at least 1.0 mA at Voh
Source current of 0.5 mA when pulled down to 3.0V
Sink current of at least 12.4 mA at Vol

- 3. TTL Vilits also referred to as a zero.
- 4. TTL Vih is also referred to as a one.
- 5. At 5.25 V over full operating temperature range.

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AC characteristics

sym	parameter	min	fa.\x	units	makee
tas	Affin 12 has James a			0.12.23	notes
tah	AB-A3 to /DEV, fe	48		nS	_
tds	/DEV, re to AO-A3 invalid	-1		-	setup
	data to (Q3 OR /DEV), re	5₿		n\$	addr hold
tdh	(V3 UK /DEV), re to date	10		nS	setup
t da	/uny, is to data out		190	n\$	data hold
td s1	/DEV low		180	nS	access, 1.
tdah	/DEV high	200	-	n\$	6.
tde	DEV to /ENBLE OF /WRREQ	450	_	n\$	•
tdph	/DEV to PHASEX		5 66	n \$	2.
trdb	RDDATA high time		500	n S	2.
tckh	FCLK high time	306	_	ກ\$	5.
tck1	FCLE low time	5\$	200	nS	J.
tckp	AND TOW SIDE	50	200		
tckpt	FCLK period, with timer	126	143	n\$	
texpt	berind Bo times	120		n.\$	
tqdal	ys, se to /DEV. fe	i	500	n \$	11.
tqdsh	Q3, re to /DEV. re	i	200	22	7.
tq3h	Q3 high	-	200	DS.	7
tq31	Q3 low	25	306	72.\$	7.
tdasbh	DØ-6 valid to D7 re	198		nS	7.
tres	RESET low time	5帅		n\$	8.
truch	/RESET to /WRREQ high	5 0\$		nS	16.
tsj	sandian tto MKKEN high		300	nS.	104
tckwr	sampling jitter		10	=	•
turj	write clock, re to WRDATA		506 ·	nS -S	4.
_	Atten data litter	—		n S	9.
cb	input pin capacitance		15	nS	9.
	- · - -		15	₽₽	

notes

- 1. Load = 136 pF and 8 LS TIL loads
- 2. Load = 100 pf and rated maximum current
- 3. fe = falling edge (TTL high to low) re = rising edgs
- 4. tsj is the uncertainty window in sampling the asynchronous input RDDATA and synchronizing it internally with CLK at any constant Vcc and temperature.

5. trdh and trdl must be at least twice the period of CLK to be properly synchronized.

6. the time between 2 succesive /DEV selects will be greater than 2 CLK periods, and in synchronous mode will be no less than 1 Q3 period. /DEV may be held low indefinitly.

7. These apply to the synchonous mode only. In other modes Q3 may be held

- 8. If, when /DEV is low, data on DO-7 is changing to a word with D7 high, the data on DD-6 must become valid before the rising edge of D7 .
- 9. tckwr is the time from FCLK, re, in asynchronous mode, or Q3, re, in synchronous mode, to changes in the output WRDATA, driving a load of

twrj is the change in toker from edge to edge of WRDATA at any constant

- 18. for test purposes tres must be at least 24 times tokp .
- 11. Jokpt is max FCLK period with 1-second timer disabled.

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This specification is confidential to Apple and contains proprietary information.

changes from earlier specs

A\$\mathref{g}\$-3 pinout corrected |
|ENBL1 and |ENBL2 pinout corrected |
| tdmsbh specified |
| latch mode added (change to breadboard also)

changes from rev#11 spec (4/16/82)

DB-7 pinout changed to facilitate IC layout write jitter specified

changes from revf12 spec (5/5/82)

Address setup time changed to 40 nS

changes from rev#14 spec (6/4/82)

LMotor-On different from Motor-On Phase lines sink 2.4 mA tres test condition added underrun and other nomenclatured cleared up

changes from rev#17 spec (8/17/82)

read data stall time changed to 4 CLRs relaxed AC and DC characteristics

rhm \$2/\$5/82 bcs \$1/11/82 ws 1\$/2\$/81 woz 1978,79

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